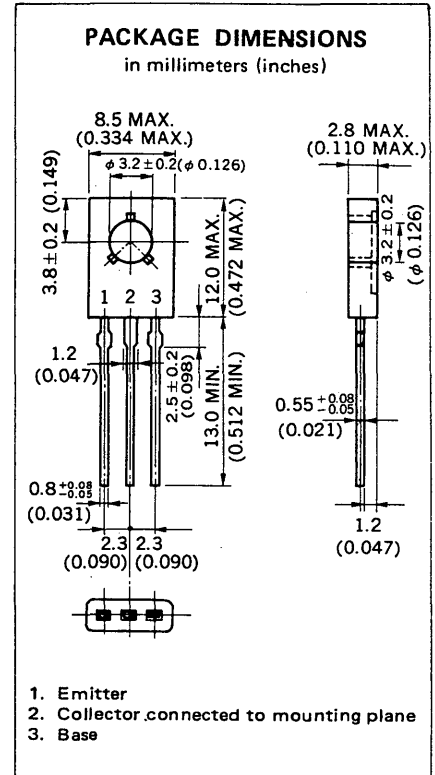


**DESCRIPTION** The 2SC2688 is designed for use in Color TV chroma output circuits.

- FEATURES**
- High Electrostatic-Discharge-Resistance. (E-B reverse bias,  $C = 2300 \text{ pF}$ ) ESDR : TYP. 1 000 V
  - Low  $C_{re}$ , High  $f_T$   
 $C_{re} \leq 3.0 \text{ pF}$  ( $V_{CB} = 30 \text{ V}$ )  
 $f_T \geq 50 \text{ MHz}$  ( $V_{CE} = 30 \text{ V}$ ,  $I_E = -10 \text{ mA}$ )

**ABSOLUTE MAXIMUM RATINGS**

- Maximum Temperatures  
 Storage Temperature .....  $-55$  to  $+150 \text{ }^\circ\text{C}$   
 Junction Temperature .....  $150 \text{ }^\circ\text{C}$  Maximum
- Maximum Power Dissipations  
 Total Power Dissipation ( $T_a = 25 \text{ }^\circ\text{C}$ ) .....  $1.25 \text{ W}$   
 Total Power Dissipation ( $T_c = 25 \text{ }^\circ\text{C}$ ) .....  $10 \text{ W}$
- Maximum Voltages and Current ( $T_a = 25 \text{ }^\circ\text{C}$ )  
 $V_{CBO}$  Collector to Base Voltage .....  $300 \text{ V}$   
 $V_{CEO}$  Collector to Emitter Voltage .....  $300 \text{ V}$   
 $V_{EBO}$  Emitter to Base Voltage .....  $5.0 \text{ V}$   
 $I_C$  Collector Current .....  $200 \text{ mA}$



**ELECTRICAL CHARACTERISTICS ( $T_a = 25 \text{ }^\circ\text{C}$ )**

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$h_{FE}$	DC Current Gain	40	80	250		$V_{CE} = 10 \text{ V}$ , $I_C = 10 \text{ mA}^*$
$f_T$	Gain Bandwidth Product	50	80		MHz	$V_{CE} = 30 \text{ V}$ , $I_E = -10 \text{ mA}$
$C_{re}$	Feedback Capacitance			3.0	pF	$V_{CB} = 30 \text{ V}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$
$I_{CBO}$	Collector Cutoff Current			100	nA	$V_{CB} = 200 \text{ V}$ , $I_E = 0$
$I_{EBO}$	Emitter Cutoff Current			100	nA	$V_{EB} = 5.0 \text{ V}$ , $I_C = 0$
$V_{CE(sat)}$	Collector Saturation Voltage			1.5	V	$I_C = 50 \text{ mA}$ , $I_B = 5.0 \text{ mA}$

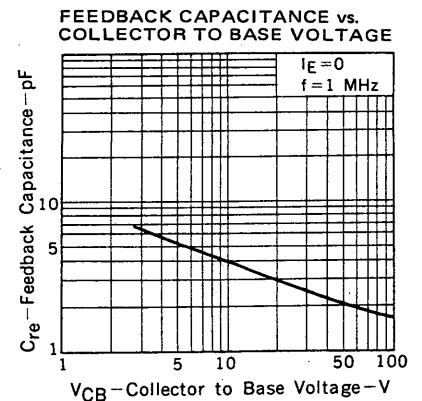
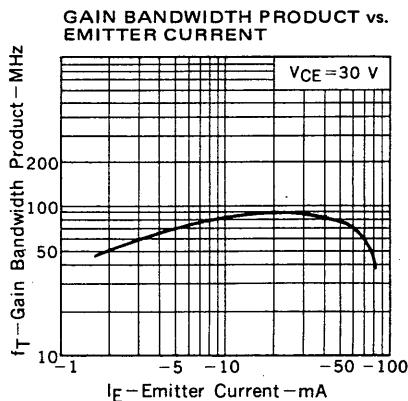
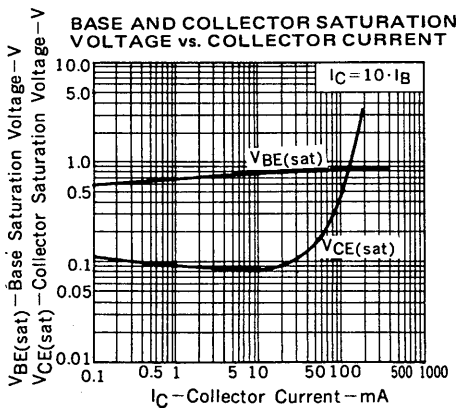
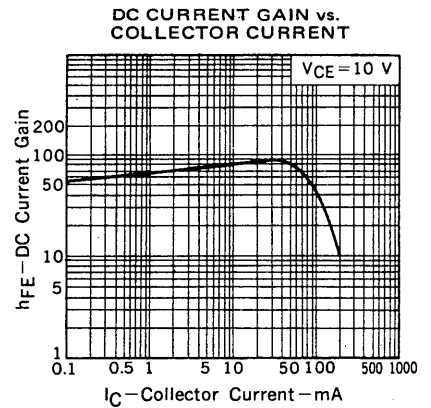
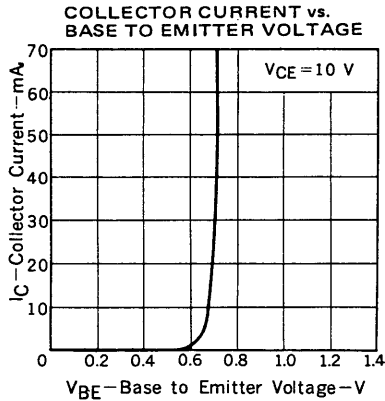
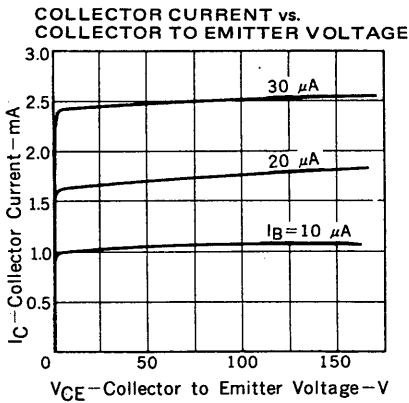
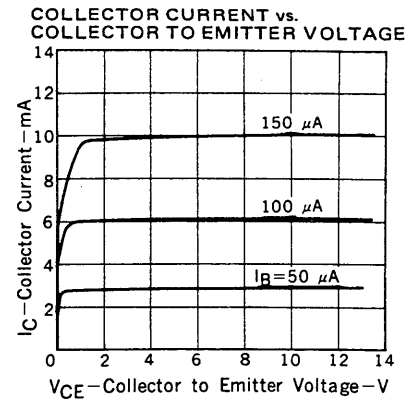
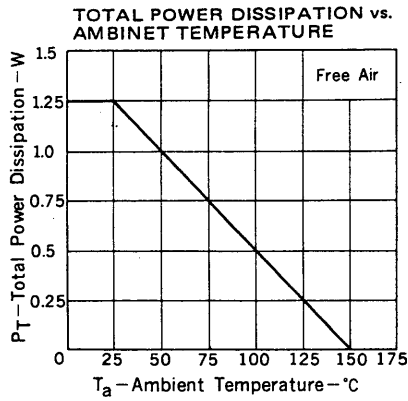
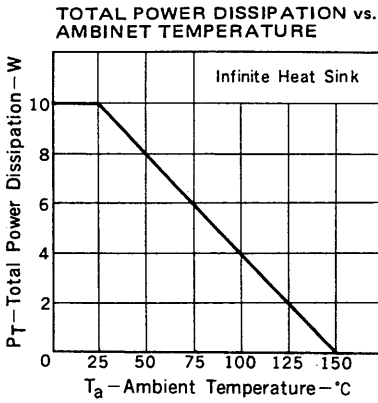
\*Pulsed  $PW \leq 350 \mu\text{s}$ , Duty Cycle  $\leq 2 \%$

**Classification of  $h_{FE}$**

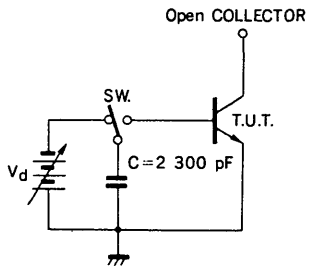
Rank	N	M	L	K
Range	40 to 80	60 to 120	100 to 200	160 to 250

Test Conditions :  $V_{CE} = 10 \text{ V}$ ,  $I_C = 10 \text{ mA}$

TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )



## BURNOUT TEST CIRCUIT BY DISCHARGE OF CAPACITOR



## TEST CONDITION

- 1) E-B reverse bias
- 2)  $C = 2300 \text{ pF}$
- 3) Apply one shot pulse to T.U.T. (Transistor Under the Test) by SW.

## JUDGEMENT

REJECT;  $BV_{EBO}$  waveform defect  
As a result if T.U.T. is not rejected, apply higher voltage to capacitor and test again.